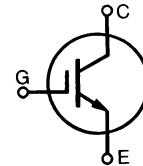


Low $V_{CE(sat)}$ IGBT High Speed IGBT

IXGH 12N100
IXGH 12N100A

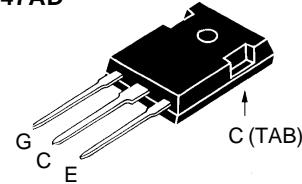
V_{CES}	I_{C25}	$V_{CE(sat)}$
1000 V	24 A	3.5 V
1000 V	24 A	4.0 V



Symbol Test Conditions

Symbol	Test Conditions	Maximum Ratings
V_{CES}	$T_J = 25^\circ\text{C}$ to 150°C	1000 V
V_{CGR}	$T_J = 25^\circ\text{C}$ to 150°C ; $R_{GE} = 1 \text{ M}\Omega$	1000 V
V_{GES}	Continuous	± 20 V
V_{GEM}	Transient	± 30 V
I_{C25}	$T_c = 25^\circ\text{C}$	24 A
I_{C90}	$T_c = 90^\circ\text{C}$	12 A
I_{CM}	$T_c = 25^\circ\text{C}$, 1 ms	48 A
SSOA (RBSOA)	$V_{GE} = 15 \text{ V}$, $T_{VJ} = 125^\circ\text{C}$, $R_G = 150 \Omega$ Clamped inductive load, $L = 300 \mu\text{H}$	$I_{CM} = 24$ A @ 0.8 V_{CES}
P_c	$T_c = 25^\circ\text{C}$	100 W
T_J		-55 ... +150 $^\circ\text{C}$
T_{JM}		150 $^\circ\text{C}$
T_{stg}		-55 ... +150 $^\circ\text{C}$
M_d	Mounting torque (M3)	1.13/10 Nm/lb.in.
Weight		6 g
Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s		300 $^\circ\text{C}$

TO-247AD



G = Gate C = Collector
E = Emitter TAB = Collector

Symbol Test Conditions

Symbol	Test Conditions	Characteristic Values		
		($T_J = 25^\circ\text{C}$, unless otherwise specified)		
		Min.	Typ.	Max.
BV_{CES}	$I_C = 3 \text{ mA}$, $V_{GE} = 0 \text{ V}$ BV_{CES} temperature coefficient	1000		V
			0.072	%/K
$V_{GE(th)}$	$I_C = 500 \mu\text{A}$, $V_{GE} = V_{GE}$ $V_{GE(th)}$ temperature coefficient	2.5	5.5	V
			-0.192	%/K
I_{CES}	$V_{CE} = 0.8 V_{CES}$ $V_{GE} = 0 \text{ V}$	$T_J = 25^\circ\text{C}$	250	μA
		$T_J = 125^\circ\text{C}$	1	mA
I_{GES}	$V_{CE} = 0 \text{ V}$, $V_{GE} = \pm 20 \text{ V}$		± 100	nA
$V_{CE(sat)}$	$I_C = I_{C90}$, $V_{GE} = 15 \text{ V}$	12N100 12N100A	3.5 4.0	V

Features

- International standard package JEDEC TO-247 AD
- 2nd generation HDMOS™ process
- Low $V_{CE(sat)}$
 - for low on-state conduction losses
- High current handling capability
- MOS Gate turn-on
 - drive simplicity
- Voltage rating guaranteed at high temperature (125°C)

Applications

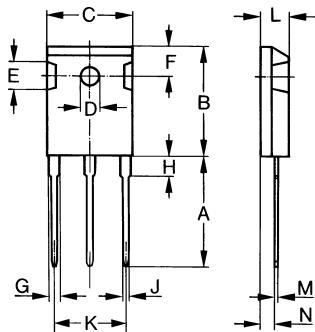
- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switch-mode and resonant-mode power supplies

Advantages

- Easy to mount with 1 screw (isolated mounting screw hole)
- High power density

Symbol	Test Conditions	Characteristic Values		
		($T_J = 25^\circ\text{C}$, unless otherwise specified)	Min.	Typ.
g_{fs}	$I_C = I_{C90}$; $V_{CE} = 10 \text{ V}$, Pulse test, $t \leq 300 \mu\text{s}$, duty cycle $\leq 2 \%$	6	10	S
C_{ies} C_{oes} C_{res}	$V_{CE} = 25 \text{ V}$, $V_{GE} = 0 \text{ V}$, $f = 1 \text{ MHz}$	750	pF	
		80	pF	
		30	pF	
Q_g Q_{ge} Q_{gc}	$I_C = I_{C90}$, $V_{GE} = 15 \text{ V}$, $V_{CE} = 0.5 V_{CES}$	65	90	nC
		8	nC	
		24	45	nC
$t_{d(on)}$ t_{ri} $t_{d(off)}$ t_{fi} E_{off}	Inductive load, $T_J = 25^\circ\text{C}$ $I_C = I_{C90}$, $V_{GE} = 15 \text{ V}$, $L = 300 \mu\text{H}$, $V_{CE} = 0.8 V_{CES}$, $R_G = R_{off} = 120 \Omega$ Remarks: Switching times may increase for V_{CE} (Clamp) $> 0.8 V_{CES}$, higher T_J or increased R_G	100		ns
		200		ns
		850	1000	ns
		800	1000	ns
		500	700	ns
		12N100	2.5	mJ
$t_{d(on)}$ t_{ri} E_{on} $t_{d(off)}$ t_{fi} E_{off}	Inductive load, $T_J = 125^\circ\text{C}$ $I_C = I_{C90}$, $V_{GE} = 15 \text{ V}$, $L = 300 \mu\text{H}$ $V_{CE} = 0.8 V_{CES}$, $R_G = R_{off} = 120 \Omega$ Remarks: Switching times may increase for V_{CE} (Clamp) $> 0.8 V_{CES}$, higher T_J or increased R_G	100		ns
		200		ns
		1.1		mJ
		900		ns
		12N100	1250	ns
		12N100A	950	ns
R_{thJC} R_{thCK}		12N100	3.5	mJ
		12N100A	2.2	mJ

TO-247 AD (IXGH) Outline



Dim.	Millimeter Min.	Millimeter Max.	Inches Min.	Inches Max.
A	19.81	20.32	0.780	0.800
B	20.80	21.46	0.819	0.845
C	15.75	16.26	0.610	0.640
D	3.55	3.65	0.140	0.144
E	4.32	5.49	0.170	0.216
F	5.4	6.2	0.212	0.244
G	1.65	2.13	0.065	0.084
H	-	4.5	-	0.177
J	1.0	1.4	0.040	0.055
K	10.8	11.0	0.426	0.433
L	4.7	5.3	0.185	0.209
M	0.4	0.8	0.016	0.031
N	1.5	2.49	0.087	0.102

IXGH12N100/A characteristic curves may be found in the IXGH12N100U/AU1 data sheet.